

PATENT
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Docket No. 1981036

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NEW APPLICATION TRANSMITTAL - UTILITY

Transmitted herewith for filing is the patent application of Yean Kuen FANG, Wen Rong CHANG, Shyh Fann TING, Hon KUAN, and Cheng Nan CHANG for "METHOD OF GROWING SINGLE CRYSTAL GALLIUM NITRIDE ON SILICON SUBSTRATE".

1. Type Of Application

This application is an original utility application.

2. Benefit Of Prior Application

Applicant claims priority of prior Taiwan application, serial number 091124151, filed 10/16/2002.

3. Fee Calculation

CLAIMS AS FILED

Basic Fee = \$750.00

Total: 21 - 20 = 1 x \$18.00 = 18.00

Ind.: 1 - 3 = 0 x \$84.00 = 0.00

Multiple dependent: 0 x \$280.00 = 0.00

Basic Filing Fee Calculation = \$768.00

4. Fee Payment Being Made At This Time

Required Fees:

Basic Filing Fee \$768.00

Total Fees \$768.00

Please charge the above and any deficiencies in fees to Deposit Acct # 16-2497.

5. Papers Enclosed Which Are Required For Filing Date Under 37 CFR 1.53(b)

14 Pages of specification

5 Pages of claims

2 Page of abstract

4 Sheets of formal drawings

6. Declaration or Oath

A Combined Declaration and Power of Attorney executed by each inventor is enclosed herewith.

7. Certificate of Mailing (37 CFR 1.10): I hereby certify that this paper (along with any referred to as being attached or enclosed) is being deposited with the United States Postal Service on the date shown below with sufficient postage as Express Mail in an envelope addressed to: Mail Stop New Applications, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Respectfully submitted,


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